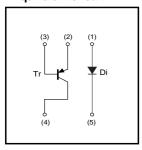
# Low-frequency transistor **UML1N**

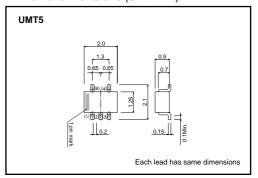
#### ●Features

 The 2SA1037AK and a diode are housed independently in a UMT package.

# ●Equivalent circuit



## ●External dimensions (Unit : mm)



## Packaging specifications

Туре	FML10
Package	SMT5
Marking	L10
Code	TR
Basic ordering unit(pieces)	3000

# ● Absolute maximum ratings (Ta=25°C)

Tr

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-60	V
Collector-emitter voltage	Vceo	-50	V
Emitter-base voltage	VEBO	-6	V
Collector current	lc	-0.15	A
Collector power dissipatio	Pc	0.15	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Di

Parameter	Symbol	Limits	Unit
DC reverse voltage	VR	80	V
Peak reverse voltage	V <sub>RM</sub>	80	V
Mean rectifying current	lo	0.1	A
Peak forward voltage	Iгм	0.3	A
Surge current	Isurge	4	A
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C
Specified I/O frequencies	f	100	MHz

## ●Electrical characteristics (Ta=25°C)

Tr

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	-50	-	-	V	Ic=-1mA
Collector-base breakdown voltage	ВУсво	-60	-	-	V	Ic= -50μA
Emitter-base breakdown voltage	ВVево	-6	-	-	V	IE= -50μA
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb= -60V
Emitter cutoff current	ІЕВО	-	-	-0.1	μΑ	V <sub>EB</sub> = -5V
Collector-emitter saturation voltage	VcE(sat)	-	-	-0.5	V	Ic/I <sub>B</sub> = -50mA/ -5mA
DC current transfer ratio	hfe	120	-	560	-	Vce= -6V, Ic= -1mA
Transition frequency	f⊤	-	140	-	MHz	Vc=-12V, I= 2mA, f= 100MHz
Output capacitance	Cob	-	4	5	pF	Vcb= -12V, IE= 0A, f= 1MHz

Di

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	-	-	1.2	V	I=100mA
Reverse current	l <sub>R</sub>	-	-	0.1	μΑ	V <sub>R</sub> =70V
Capacitance between terminals	Ст	-	-	3.5	pF	V <sub>R</sub> =6V, f=1MHz
Reverse recovery time	trr	-	-	4	ns	V <sub>R</sub> =6V, I <sub>F</sub> =5mA, RL=50Ω

#### •Electrical characteristic curves

Tr

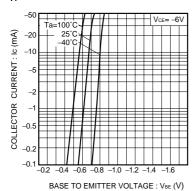


Fig.1 Grounded emitter propagation characteristics

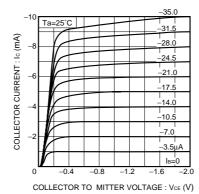


Fig.2 Grounded emitter output characteristics (I)

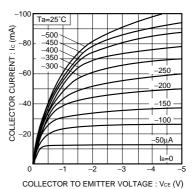


Fig.3 Grounded emitter output characteristics (II)

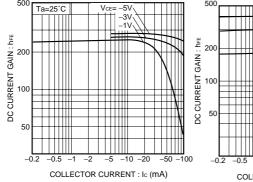


Fig.4 DC current gain vs. collector current (I)

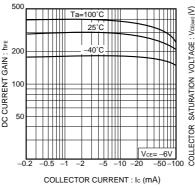


Fig.5 DC current gain vs. collector current (II)

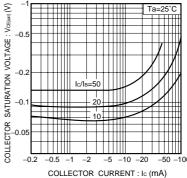


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

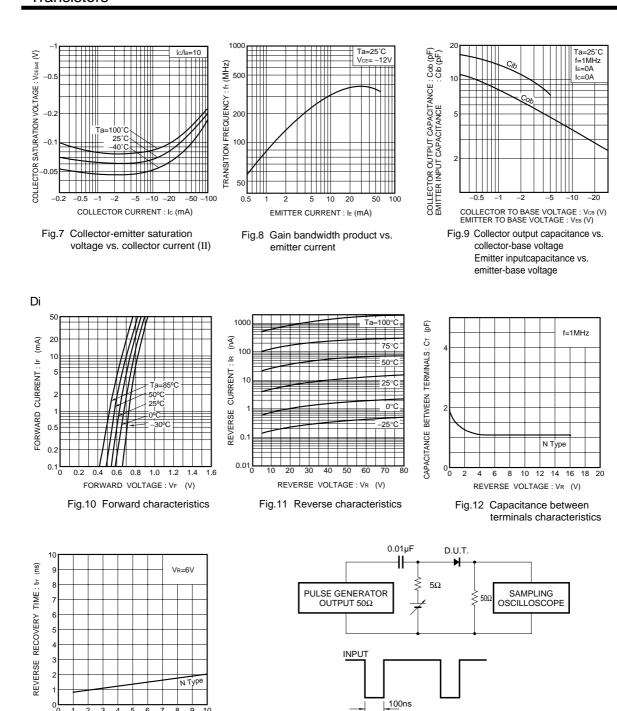


Fig.14 Reverse recovery time (t<sub>rr</sub>) measurement circuit

OUTPUT

FORWARD CURRENT : IF (mA)

Fig.13 Reverse recovery time

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Appendix1-Rev1.1